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FXLH1T45 Low Voltage 1-Bit Bi-directional Level Translator with Configurable Voltage Supplies and Bushold Data Inputs

Features

- Bi-directional interface between any 2 levels from 1.1V to 3.6V
- Fully configurable: Inputs track V_{CC} level
- Non-preferential power-up sequencing; either V_{CC} may be powered-up first
- Outputs remain in 3-STATE until active V_{CC} level is reached
- Outputs switch to 3-STATE if either V_{CC} is at GND
- Power off protection
- Bushold on data inputs eliminates the need for external pull-up/pull-down resistors
- Control input (T/R) levels are referenced to V_{CCA} voltage
- Packaged in the MicroPak 6 (1.0mm x 1.45mm)
- ESD protections exceeds:
 4kV HBM ESD (per JESD22-A114 & Mil Std 883e 3015.7)
 - 8kV HBM I/O to GND ESD (per JESD22-A114 & Mil Std 883e 3015.7)
 - 1kV CDM ESD (per ESD STM 5.3)
 - 200V MM ESD (per JESD22-A115 & ESD STM5.2)

General Description

The FXLH1T45 is a single bit configurable dual-voltage supply translator designed for both uni-directional and bi-directional voltage translation between two logic levels. The device allows translation between voltages as high as 3.6V to as low as 1.1V. The A port tracks the V_{CCA} level, and the B port tracks the V_{CCB} level. This allows for bi-directional voltage translation over a variety of voltage levels: 1.2V, 1.5V, 1.8V, 2.5V, and 3.3V.

The device remains in 3-STATE until both V_{CC}s reach active levels allowing either V_{CC} to be powered-up first. Internal power down control circuits place the device in 3-STATE if either V_{CC} is removed.

The Transmit/Receive (T/ $\overline{R})$ input determines the direction of data flow through the device. The FXLH1T45 is designed so that the control pin (T/ \overline{R}) is supplied by V_{CCA}.

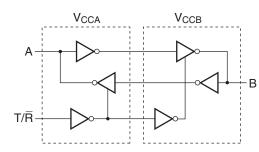
Ordering Information

Order Number	Package Number	Pb-Free	Package Description	Supplied As
FXLH1T45L6X	MAC06A	Yes	6-Lead MicroPak, 1.0mm Wide	5k Units on Tape and Reel

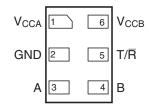
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April 2007

Functional Diagram



Connection Diagram



(Top Through View)

Pin Assignment

Pin Number	Terminal Name
1	V _{CCA}
2	GND
3	A
4	В
5	T/R
6	V _{CCB}

Pin Descriptions

Pin Names	Description						
T/R	Transmit/Receive Input						
A	Side A Input or Output						
В	Side B Input or Output						
V _{CCA}	Side A Power Supply						
V _{CCB}	Side B Power Supply						

Function Table

Inputs (T/R)	Outputs
L	Bus B Data to Bus A
Н	Bus A Data to Bus B

H = HIGH Logic Level

L = LOW Logic Level

Power-Up/Power-Down Sequencing

FXL translators offer an advantage in that either V_{CC} may be powered up first. This benefit derives from the chip design. When either V_{CC} is at 0V, outputs are in a HIGH-Impedance state. To ensure that bus contention, excessive currents, or oscillations do not occur, a proper power-up sequence is recommended.

The recommended power-up sequence is the following:

- 1. Apply power to either $V_{\mbox{\scriptsize CC}}.$
- Apply power to the T/R input (Logic HIGH for A-to-B operation; Logic LOW for B-to-A operation) and to the respective data inputs (A Port or B Port). This may occur at the same time as Step 1.
- 3. Apply power to other $\ensuremath{\mathsf{V}_{\mathsf{CC}}}$.

The recommended power-down sequence is the follow-ing:

- 1. Remove power from either V_{CC} .
- 2. Remove power from other V_{CC} .

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Rating
V _{CCA} , V _{CCB}	Supply Voltage	–0.5V to +4.6V
VI	DC Input Voltage	
	I/O Port A	–0.5V to +4.6V
	I/O Port B	–0.5V to +4.6V
	Control Input (T/R)	–0.5V to +4.6V
Vo	Output Voltage ⁽¹⁾	
	Outputs 3-STATE	-0.5V to +4.6V
	Outputs Active (A _n)	-0.5V to V _{CCA} + 0.5V
	Outputs Active (B _n)	$-0.5V$ to $V_{CCB} + 0.5V$
I _{IK}	DC Input Diode Current @ V _I < 0V	–50mA
Ι _{ΟΚ}	DC Output Diode Current @	
	V _O < 0V	–50mA
	$V_{O} > V_{CC}$	+50mA
I _{OH} / I _{OL}	DC Output Source/Sink Current	-50mA / +50mA
I _{CC}	DC V _{CC} or Ground Current per Supply Pin	±100mA
T _{STG}	Storage Temperature Range	−65°C to +150°C

Recommended Operating Conditions⁽²⁾

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Rating
V_{CCA} or V_{CCB}	Power Supply Operating	1.1V to 3.6V
	Input Voltage	
	Port A	0.0V to 3.6V
	Port B	0.0V to 3.6V
	Control Input (T/R)	0.0V to V _{CCA}
	Output Current in I _{OH} /I _{OL} with V _{CC @}	
	3.0V to 3.6V	±24mA
	2.3V to 2.7V	±18mA
	1.65V to 1.95V	±6mA
	1.4V to 1.65V	±2mA
	1.1V to 1.4V	±0.5mA
T _A	Free Air Operating Temperature	−40°C to +85°C
$\Delta t/\Delta V$	Maximum Input Edge Rate V _{CCA/B} = 1.1V to 3.6V	10ns/V

Notes:

1. $I_{\rm O}$ Absolute Maximum Rating must be observed.

2. All unused inputs and I/O pins must be held at $V_{CCI}\xspace$ or GND.

Symbol	Parameter	Conditions	V _{CCI} (V)	$V_{CCO}(V)$	Min.	Тур.	Max.	Units	
V _{IH}	High Level Input	Data Inputs A _n , B _n	2.7–3.6	1.1–3.6	2.0	_	_	V	
	Voltage ⁽³⁾		2.3–2.7		1.6	_	_		
			1.65-2.3		0.65 x V _{CCI}	_	-		
			1.4–1.65	1	0.65 x V _{CCI}	-	-		
			1.1–1.4	1	0.9 x V _{CCI}	-	-		
		Control Pin T/R	2.7–3.6	1.1–3.6	2.0	-	_		
		(Referenced to V _{CCA})	2.3–2.7	1	1.6	_	-		
			1.65-2.3	1	0.65 x V _{CCA}	-	_		
			1.4-1.65	1	0.65 x V _{CCA}	-	_		
			1.1–1.4	1	0.9 x V _{CCA}	_	-		
V _{IL}	Low Level Input	Data Inputs A _n , B _n	2.7–3.6	1.1–3.6	-	_	0.8	V	
	Voltage ⁽³⁾		2.3–2.7	1	-	_	0.7		
			1.65-2.3	-	-	_	0.35 x V _{CCI}	-	
			1.4-1.65		-	_	0.35 x V _{CCI}		
			1.1–1.4	-	-	_	0.1 x V _{CCI}		
		Control Pin T/R	2.7–3.6	1.1–3.6	_	_	0.8		
		(Referenced to V_{CCA})	2.3–2.7		_	_	0.7		
			1.65-2.3		_	_	0.35 x V _{CCA}		
			1.4-1.65		_	_	0.35 x V _{CCA}		
			1.1–1.4	-	_	_	0.1 x V _{CCA}		
V _{OH}	High Level Output	I _{OH} = -100μA	1.1–3.6	1.1–3.6	V _{CC0} -0.2	_	-	V	
	Voltage ⁽⁴⁾	$I_{OH} = -12mA$	2.7	2.7	2.2	_	-		
		$I_{OH} = -18 \text{mA}$	3.0	3.0	2.4	-	_		
		$I_{OH} = -24mA$	3.0	3.0	2.2	-	_		
		I _{OH} = -6mA	2.3	2.3	2.0	_	-		
		$I_{OH} = -12mA$	2.3	2.3	1.8	_	-		
		I _{OH} = -18mA	2.3	2.3	1.7	_	-		
		I _{OH} = -6mA	1.65	1.65	1.25	_	-		
		I _{OH} = -2mA	1.4	1.4	1.05	_	-		
		I _{OH} = -0.5mA	1.1	1.1	0.75 x V _{CC0}	_	-		
V _{OL}	Low Level Output	I _{OL} = 100μA	1.1–3.6	1.1–3.6	-	_	0.2	V	
	Voltage ⁽⁴⁾	I _{OL} = 12mA	2.7	2.7	-	_	0.4		
		I _{OL} = 18mA	3.0	3.0	-	_	0.4		
		I _{OL} = 24mA	3.0	3.0	-	-	0.55		
		I _{OL} =12mA	2.3	2.3	-	-	0.4		
		I _{OL} = 18mA	2.3	2.3	-	-	0.6	1	
		I _{OL} = 6mA	1.65	1.65	-	-	0.3	1	
		$I_{OL} = 2mA$	1.4	1.4	-	-	0.35	1	
		$I_{OL} = 0.5 \text{mA}$	1.1	1.1	-	_	0.3 x V _{CC0}	1	
Ι	Input Leakage Current Control Pins		1.1–3.6	3.6	-	_	±1.0	μA	

Symbol	Parameter	Conditions	V _{CCI} (V)	V _{CCO} (V)	Min.	Тур.	Max.	Unit	
I _{I(HOLD)}	Bushold Input	V _{IN} = 0.8	3.0	3.0	75.0	-	-	μΑ	
	Minimum Drive Current	V _{IN} = 2.0	3.0	3.0	-75.0	-	_		
	Current	V _{IN} = 0.7	2.3	2.3	45.0	-	_		
		V _{IN} = 1.6	2.3	2.3	-45.0	-	_		
		V _{IN} = 0.57	1.65	1.65	25.0	-	_		
		V _{IN} = 1.07	1.65	1.65	-25.0	-	-		
		V _{IN} = 0.49	1.4	1.4	11.0	-	_		
		V _{IN} = 0.91	1.4	1.4	-11.0	-	_		
		V _{IN} = 0.11	1.1	1.1	_	4.0	_		
		V _{IN} = 0.99	1.1	1.1	_	-4.0	_		
I _{I(OD)}	Bushold Input	(5)	3.6	3.6	450	-	_	μA	
	Over-Drive	(6)	3.6	3.6	-450	-	_		
	Current-to-Change State	(5)	2.7	2.7	300	-	_		
		(6)	2.7	2.7	-300	-	_		
		(5)	1.95	1.95	200	-	_		
		(6)	1.95	1.95	-200	-	_		
		(5)	1.6	1.6	120	-	_		
		(6)	1.6	1.6	-120	-	-		
		(5)	1.4	1.4	80.0	-	_		
		(6)	1.4	1.4	-80.0	-	_	1	
I _{OFF}	Power Off Leakage Current		0	3.6	-	-	±10.0	μA	
		$B_n, V_{CCB} = V_{CCI},$ $V_I = 0V \text{ to } 3.6V$	0	3.6	-	-	±10.0		
I _{OZ}	3-STATE Output Leakage		0	3.6	-	-	±10.0	μA	
		$B_n, V_{CCB} = V_{CCO}, \\ V_O = 0V \text{ or } 3.6V$	0	3.6	-	-	±10.0		
I _{CCA/B}	Quiescent Supply Current ⁽⁷⁾	$V_{I} = V_{CCI}$ or GND; $I_{O} = 0$	1.1–3.6	1.1–3.6	-	-	20.0	μA	
I _{CCA}	Quiescent Supply	$V_{I} = V_{CCA}$ or GND; $I_{O} = 0$	0	1.1–3.6	_	-	-10.0	μA	
	Current	$V_{I} = V_{CCA}$ or GND; $I_{O} = 0$	1.1–3.6	0	_	-	10.0	μA	
I _{CCB}	Quiescent Supply	$V_I = V_{CCB}$ or GND; $I_O = 0$	1.1–3.6	0	_	-	-10.0	μA	
	Current	$V_I = V_{CCB}$ or GND; $I_O = 0$	0	1.1–3.6	_	-	10.0	μA	
$\Delta I_{CCA/B}$	Increase in I_{CC} per Input; Other Inputs at V_{CC} or GND	V _{IH} = 3.0	3.6	3.6	_	-	500	μΑ	

DC Electrical Characteristics (Continued)

Notes:

- 3. V_{CCI} = the V_{CC} associated with the data input under test.
- 4. V_{CCO} = the V_{CC} associated with the output under test.
- 5. An external driver must source at least the specified current to switch LOW-to-HIGH.
- 6. An external driver must source at least the specified current to switch HIGH-to-LOW.
- 7. Reflects current per supply, V_{CCA} or $V_{CCB}.$

AC Electrical Characteristics

$V_{CCA} = 3.0V$ to 3.6V

					TA	= −40°0	C to +8	5°C				
			V _{CCB} = 3.0V to 3.6V		V _{CCB} = 2.3V to 2.7V		V _{CCB} = 1.65V to 1.95V		V _{CCB} = 1.4V to 1.6V		V _{CCB} = 1.1V to 1.3V	
Symbol	Parameter	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Units
t _{PLH} , t _{PHL}	Propagation Delay A to B	0.2	3.5	0.3	3.9	0.5	5.4	0.6	6.8	1.4	22.0	ns
	Propagation Delay B to A	0.2	3.5	0.2	3.8	0.3	4.0	0.5	4.3	0.8	13.0	
t _{PZH} , t _{PZL} ⁽⁸⁾	Output Enable T/\overline{R} to B	0.4	7.2	0.5	7.6	0.7	9.1	0.8	10.5	1.6	25.7	ns
	Output Enable T/\overline{R} to A	0.4	7.3	0.4	7.8	1.0	8.8	2.0	10.5	2.8	30.0	
t _{PHZ} , t _{PLZ}	Output Disable T/\overline{R} to B	0.2	3.8	0.2	4.0	0.7	4.8	1.5	6.2	2.0	17.0	ns
	Output Disable T/\overline{R} to A	0.2	3.7	0.2	3.7	0.2	3.7	0.2	3.7	0.2	3.7	

$V_{CCA} = 2.3V$ to 2.7V

					TA	= −40°0	C to +8	5°C				
		V _{CCB} = 3.0V to 3.6V		V _{CCB} = 2.3V to 2.7V		V _{CCB} = 1.65V to 1.95V		V _{CCB} = 1.4V to 1.6V		V _{CCB} = 1.1V to 1.3V		
Symbol	Parameter	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Units
t _{PLH} , t _{PHL}	Propagation Delay A to B	0.2	3.8	0.4	4.2	0.5	5.6	0.8	6.9	1.4	22.0	ns
	Propagation Delay B to A	0.3	3.9	0.4	4.2	0.5	4.5	0.5	4.8	1.0	7.0	
t _{PZH} , t _{PZL} ⁽⁸⁾	Output Enable T/\overline{R} to B	0.4	7.8	0.6	8.2	0.7	9.6	1.0	10.9	1.6	26.0	ns
	Output Enable T/\overline{R} to A	0.5	8.0	0.6	8.5	1.2	9.3	2.0	11.5	3.0	24.0	
t _{PHZ} , t _{PLZ}	Output Disable T/\overline{R} to B	0.2	4.1	0.2	4.3	0.7	4.8	1.5	6.7	2.0	17.0	ns
	Output Disable T/\overline{R} to A	0.2	4.0	0.2	4.0	0.2	4.0	0.2	4.0	0.2	4.0	

V_{CCA} = 1.65V to 1.95V

					TA	= −40°C	C to +8	5°C				
			V _{CCB} = 3.0V to 3.6V		V _{CCB} = 2.3V to 2.7V		V _{CCB} = 1.65V to 1.95V		V _{CCB} = 1.4V to 1.6V		V _{CCB} = 1.1V to 1.3V	
Symbol	Parameter	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Units
t _{PLH} , t _{PHL}	Propagation Delay A to B	0.3	4.0	0.5	4.5	0.8	5.7	0.9	7.1	1.5	22.0	ns
	Propagation Delay B to A	0.5	5.4	0.5	5.6	0.8	5.7	1.0	6.0	1.2	8.0	
t _{PZH} , t _{PZL} ⁽⁸⁾	Output Enable T/\overline{R} to B	0.8	9.0	1.0	9.5	1.3	10.7	1.4	12.1	2.0	27.0	ns
	Output Enable T/\overline{R} to A	0.7	10.5	0.7	10.8	1.6	10.9	2.5	13.0	3.2	25.0	
t _{PHZ} , t _{PLZ}	Output Disable T/\overline{R} to B	0.2	5.1	0.2	5.2	0.8	5.2	1.5	7.0	2.0	17.0	ns
	Output Disable T/\overline{R} to A	0.5	5.0	0.5	5.0	0.5	5.0	0.5	5.0	0.5	5.0	

AC Electrical Characteristics (Continued)

V_{CCA} = 1.4V to 1.6V

					TA	= −40°0	C to +8	5°C				
			св = о 3.6V		V _{CCB} = 2.3V to 2.7V		V _{CCB} = 1.65V to 1.95V		св = о 1.6V	V _{CCB} = 1.1V to 1.3V		
Symbol	Parameter	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Units
t _{PLH} , t _{PHL}	Propagation Delay A to B	0.5	4.3	0.5	4.8	1.0	6.0	1.0	7.3	1.5	22.0	ns
	Propagation Delay B to A	0.6	6.8	0.8	6.9	0.9	7.1	1.0	7.3	1.3	9.5	
t _{PZH} , t _{PZL} ⁽⁸⁾	Output Enable T/\overline{R} to B	1.5	10.3	1.5	10.8	2.0	12.0	2.0	13.3	2.5	28.0	ns
	Output Enable T/\overline{R} to A	1.0	12.9	1.2	13.1	1.8	13.3	2.5	14.8	3.3	27.5	
t _{PHZ} , t _{PLZ}	Output Disable T/\overline{R} to B	0.4	6.1	0.4	6.2	0.9	6.2	1.5	7.5	2.0	18.0	ns
	Output Disable T/\overline{R} to A	1.0	6.0	1.0	6.0	1.0	6.0	1.0	6.0	1.0	6.0	

$V_{CCA} = 1.1V$ to 1.3V

			$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$									
		V _{CC} 3.0V t	с _в = о 3.6V		св ⁼ o 2.7V		°B ⁼ V to 5V		св = о 1.6V		с _в = о 1.3V	
Symbol	Parameter	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Units
t _{PLH} , t _{PHL}	Propagation Delay A to B	0.8	13.0	1.0	7.0	1.2	8.0	1.3	9.5	2.0	24.0	ns
	Propagation Delay B to A	1.4	22.0	1.4	22.0	1.5	22.0	1.5	22.0	2.0	24.0	
t _{PZH} , t _{PZL} ⁽⁸⁾	Output Enable T/\overline{R} to B	2.8	28.0	3.0	19.0	3.2	20.0	3.3	21.5	4.0	36.0	ns
	Output Enable T/\overline{R} to A	2.4	37.0	2.1	29.0	2.5	30.0	3.5	32.0	4.0	44.0	
t _{PHZ} , t _{PLZ}	Output Disable T/\overline{R} to B	1.0	15.0	0.7	7.0	1.0	8.0	2.0	10.0	2.0	20.0	ns
	Output Disable T/\overline{R} to A	2.0	15.0	2.0	12.0	2.0	12.0	2.0	12.0	2.0	12.0	

Note:

8. The enable time, t_{PZH} or t_{PZL}, is the time for the FXLH1T45 to return to active operation after a direction change. The enable time specifies the worst-case delay from the time the T/R pin is switched until a valid output signal is expected. For example, to change direction to B-to-A operation, the T/R pin is switched from HIGH-to-LOW. The enable time for this case is found by adding the disable time for T/R to B to the propagation delay for B to A. The formulas for calculating enable times are the following:

 t_{PZH} (T/ \overline{R} to A) = t_{PLZ} (T/ \overline{R} to B) + t_{PLH} (B to A)

 t_{PZL} (T/ \overline{R} to A) = t_{PHZ} (T/ \overline{R} to B) + t_{PHL} (B to A)

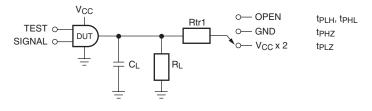
 t_{PZH} (T/ \overline{R} to B) = t_{PLZ} (T/ \overline{R} to A) + t_{PLH} (A to B)

 $t_{\mathsf{PZL}}~(\mathsf{T}/\overline{\mathsf{R}} \text{ to } \mathsf{B}) = t_{\mathsf{PHZ}}~(\mathsf{T}/\overline{\mathsf{R}} \text{ to } \mathsf{A}) + t_{\mathsf{PHL}}~(\mathsf{A} \text{ to } \mathsf{B})$

Capacitance

			$T_A = +25^{\circ}C$	
Symbol	Parameter	Conditions	Typical	Units
C _{IN}	Input Capacitance Control Pin (T/\overline{R})	V_{CCA} = V_{CCB} = 3.3V, V_{I} = 0V or $V_{CCA/B}$	4.0	pF
C _{I/O}	Input/Output Capacitance A _n , B _n Ports	V_{CCA} = V_{CCB} = 3.3V, V_{I} = 0V or $V_{CCA/B}$	5.0	pF
C _{PD}	Power Dissipation Capacitance	$\label{eq:V_CCA} \begin{split} V_{CCA} &= V_{CCB} = 3.3 \text{V}, \ \text{V}_{I} = 0 \text{V or } \text{V}_{CC}, \\ \text{F} &= 10 \text{MHz} \end{split}$	20.0	pF

AC Loading and Waveforms

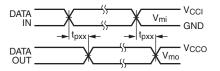


Test	Switch
t _{PLH} , t _{PHL}	OPEN
t _{PLZ}	$ \begin{array}{l} V_{CCO} \ x \ 2 \ at \ V_{CCO} = 3.3 \pm 0.3 V, \ 2.5 V \pm 0.2 V, \\ 1.8 V \pm 0.15 V, \ 1.5 V \pm 0.1 V, \ 1.2 V \pm 0.1 V \end{array} $
t _{PHZ}	GND

Figure 1. AC Test Circuit

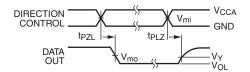
AC Load Table

V _{CCO} C _L		RL	Rtr1
$1.2V\pm0.1V$	15pF	2kΩ	2kΩ
1.5V ± 0.1V	15pF	2kΩ	2kΩ
1.8V ± 0.15V	15pF	2kΩ	2kΩ
$2.5V\pm0.2V$	15pF	2kΩ	2kΩ
$3.3V \pm 0.3V$	15pF	2kΩ	2kΩ



Input $t_R=t_F=2.0$ ns, 10% to 90% Input $t_R=t_F=2.5$ ns, 10% to 90%, @ V_I=3.0V to 3.6V only

Figure 2. Waveform for Inverting and Non-Inverting Functions



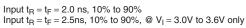
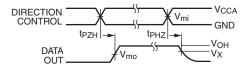
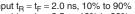


Figure 3. 3-STATE Output Low Enable and Disable Times for Low Voltage Logic





Input $t_R=t_F=2.0$ ns, 10% to 90% Input $t_R=t_F=2.5$ ns, 10% to 90%, @ V_I=3.0V to 3.6V only

Figure 4. 3-STATE Output High Enable and Disable Times for Low Voltage Logic

Symbol	V _{cc}						
Symbol	$3.3V \pm 0.3V$	$\textbf{2.5V} \pm \textbf{0.2V}$	$\textbf{1.8V} \pm \textbf{0.15V}$	$\textbf{1.5V} \pm \textbf{0.1V}$	$\textbf{1.2V} \pm \textbf{0.1V}$		
V _{mi}	V _{CCI} /2	V _{CCI} /2	V _{CCI} /2	V _{CCI} /2	V _{CCI} /2		
V _{mo}	V _{CCO} /2	V _{CCO} /2	V _{CCO} /2	V _{CCO} /2	V _{CCO} /2		
V _X	V _{OH} -0.3V	V _{OH} -0.15V	V _{OH} -0.15V	V _{OH} -0.1V	V _{OH} -0.1V		
V _Y	V _{OL} +0.3V	V _{OL} +0.15V	V _{OL} +0.15V	V _{OL} +0.1V	V _{OL} +0.1V		

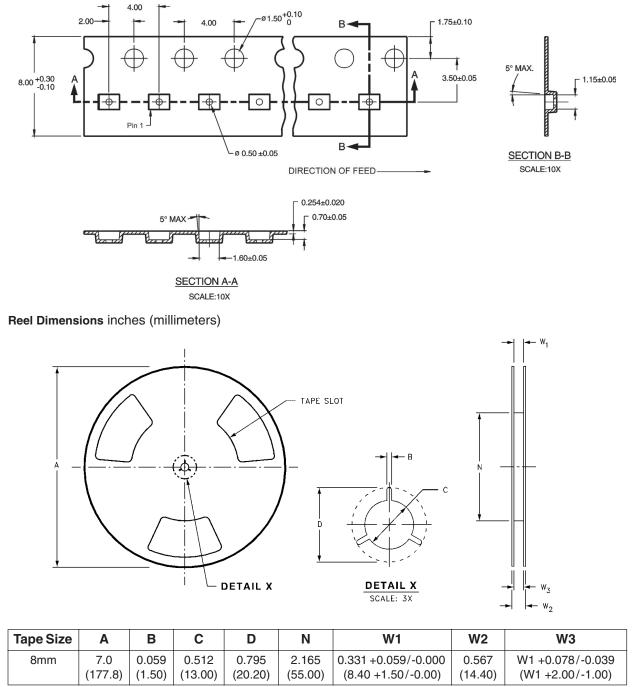
For V_{mi} : $V_{CCI} = V_{CCA}$ for Control Pin T/ \overline{R} or $V_{CCA}/2$

Tape and Reel Specification

Tape Format for MicroPak

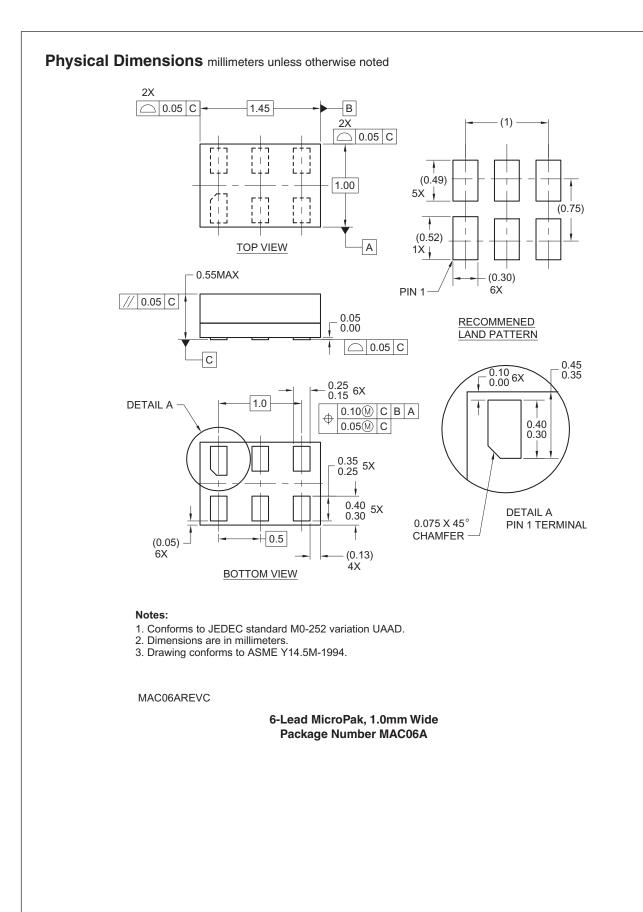
Package Designator	Tape Section	Number Cavities	Cavity Status	Cover Tape Status
L6X	Leader (Start End)	125 (typ)	Empty	Sealed
	Carrier	5000	Filled	Sealed
	Trailer (Hub End)	75 (typ)	Empty	Sealed

Tape Dimensions millimeters



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FXLH1T45 Rev. 1.0.4





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FXLH1T45 Low Voltage 1-Bit Bi-directional Level Translator with Configurable Voltage Supplies

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